

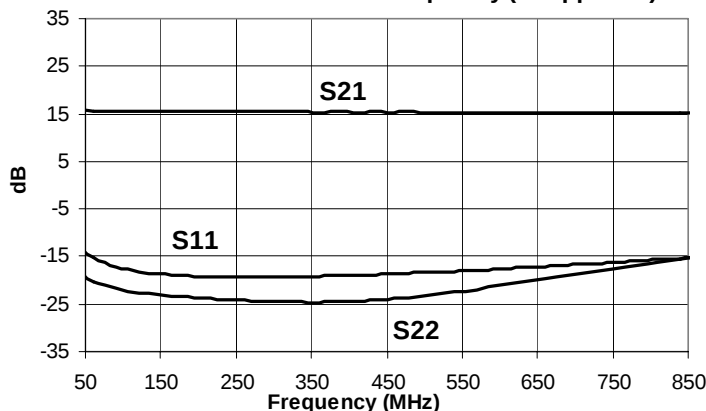


Product Description

Sirenza Microdevices' SBB-1089 is a high performance InGaP HBT MMIC amplifier utilizing a Darlington configuration with an active bias network. The active bias network provides stable current over temperature and process Beta variations. Designed to run directly from a 5V supply, the SBB-1089 does not require a dropping resistor as compared to typical Darlington amplifiers. The SBB-1089 product is designed for high linearity 5V gain block applications that require small size and minimal external components. It is internally matched to 50 ohms.

The matte tin finish on Sirenza's lead-free package utilizes a post annealing process to mitigate tin whisker formation and is RoHS compliant per EU Directive 2002/95. This package is also manufactured with green molding compounds that contain no antimony trioxide nor halogenated fire retardants.

Gain & Return Loss vs. Frequency (w/ App. Ckt.)



Symbol	Parameters	Units	Frequency	Min.	Typ.	Max.
S ₂₁	Small Signal Gain	dB	70 MHz 240 MHz 400 MHz	14	15.5 15.5 15.5	17
P _{1dB}	Output Power at 1dB Compression	dBm	70 MHz 240 MHz 400 MHz	18	19 19 19	
IP ₃	Third Order Intercept Point	dBm	70 MHz 240 MHz 400 MHz	41.5	42 43 41	
Bandwidth	S ₁₁ , S ₂₂ : Minimum 10dB Return Loss (typ.)	MHz			50 - 850	
S ₁₁	Input Return Loss	dB	70 - 500MHz		18	
S ₂₂	Output Return Loss	dB	70 - 500MHz		16	
S ₁₂	Reverse Isolation	dB	70 - 500MHz		18	
NF	Noise Figure	dB	500 MHz		3.2	4.2
V _D	Device Operating Voltage	V			5	5.3
I _D	Device Operating Current	mA		82	90	98
R _{TH} , j-l	Thermal Resistance (junction - lead)	°C/W			97	

Test Conditions: V_D = 5V I_D = 90mA Typ. OIP₃ Tone Spacing = 1MHz, Pout per tone = 0 dBm
T_L = 25°C Z_S = Z_L = 50 Ohms Tested with Bias Tees

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<http://www.sirenza.com>

Preliminary

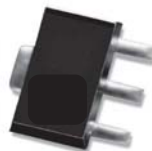
SBB-1089

SBB-1089Z



50 - 850 MHz, Cascadable

Active Bias InGaP/GaAs HBT MMIC Amplifier



Product Features

- Available in Lead Free, RoHS compliant, & Green packaging
- IP₃ = 43.1 dBm @ 240MHz
- P_{1dB} = 19.6 dBm @ 500MHz
- Single Fixed 5V Supply
- Robust 1000V ESD, Class 1C
- Patented Thermal Design & Patent Pending Bias Circuit
- Low Thermal Resistance
- MSL 1 moisture rating

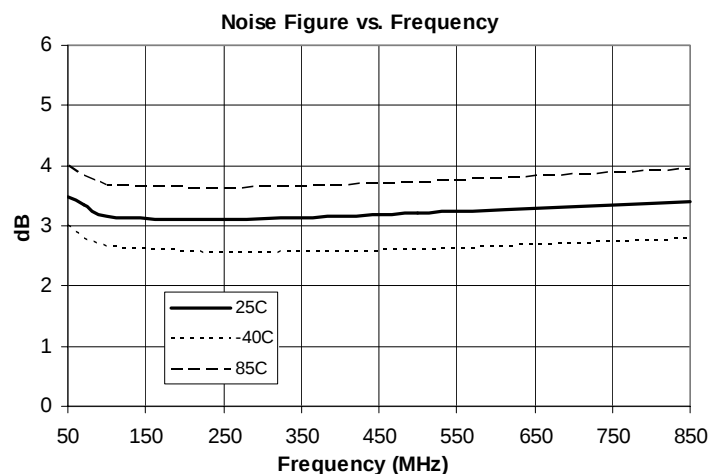
Applications

- Receiver IF Amplifier
- Cellular, PCS, GSM, UMTS
- Wireless Data, Satellite Terminals

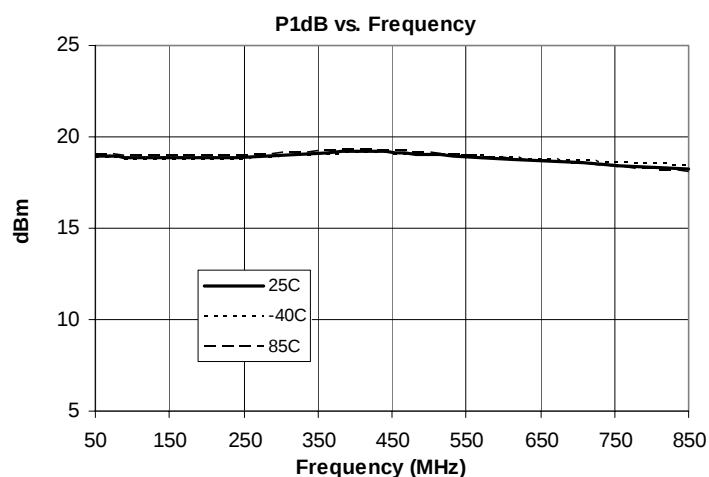
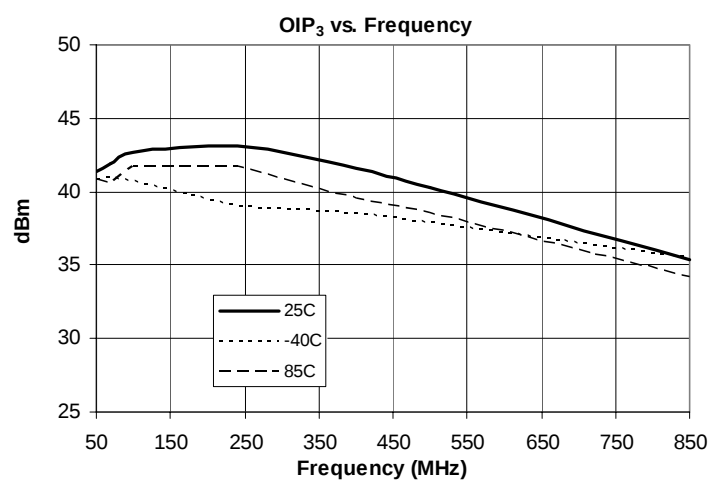
Typical RF Performance at Key Operating Frequencies (With 240 MHz Application Circuit)

Symbol	Parameter	Unit	Frequency (MHz)						
			50	70	100	240	400	500	850
S_{21}	Small Signal Gain	dB	16	15.5	15.5	15.5	15.5	15.5	15
OIP_3	Output Third Order Intercept Point	dBm	41.5	42	43	43	41	40	35
P_{1dB}	Output Power at 1dB Compression	dBm	19	19	19	19	19	19	18
S_{11}	Input Return Loss	dB	13	16	17	19	19	18	15
S_{22}	Output Return Loss	dB	18	20	21	23	24	23	17
S_{12}	Reverse Isolation	dB	18	18	18	18	18	18	18
NF	Noise Figure	dB	3.5	3.3	3.2	3.1	3.2	3.2	3.4

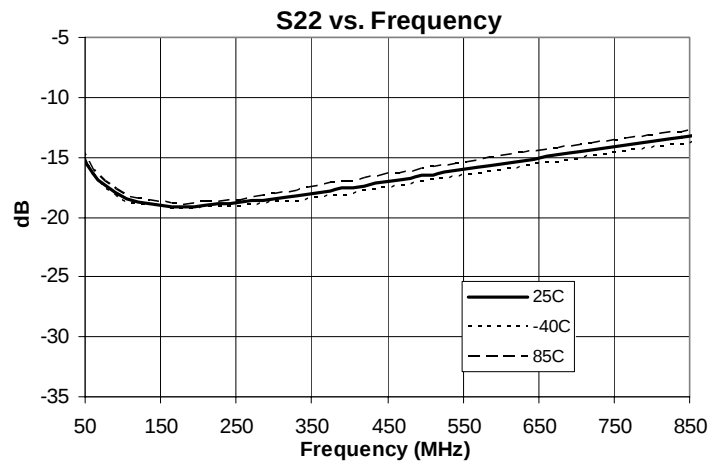
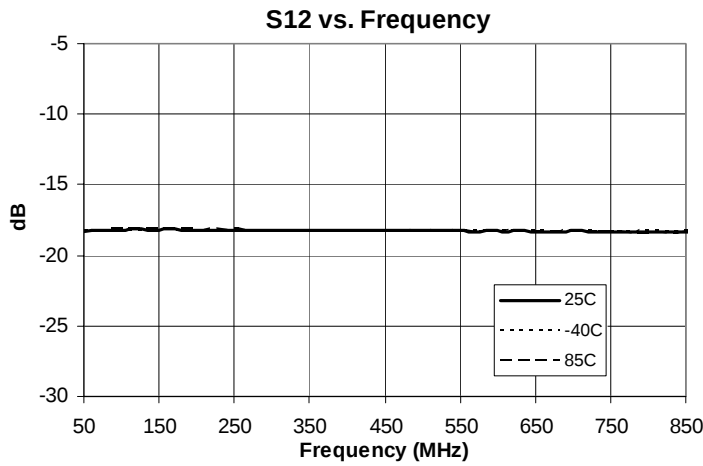
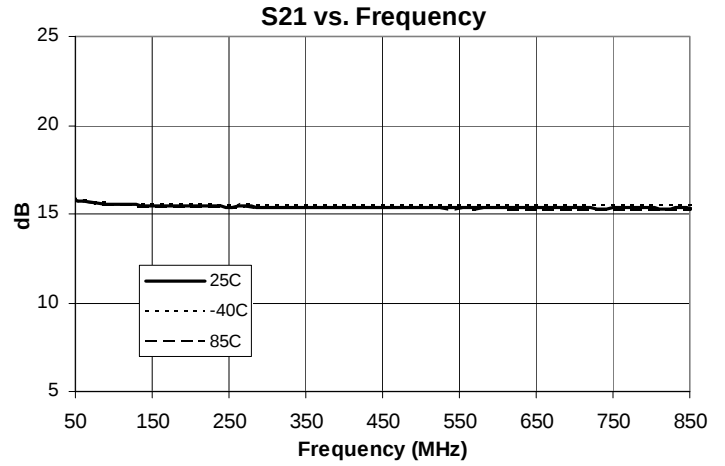
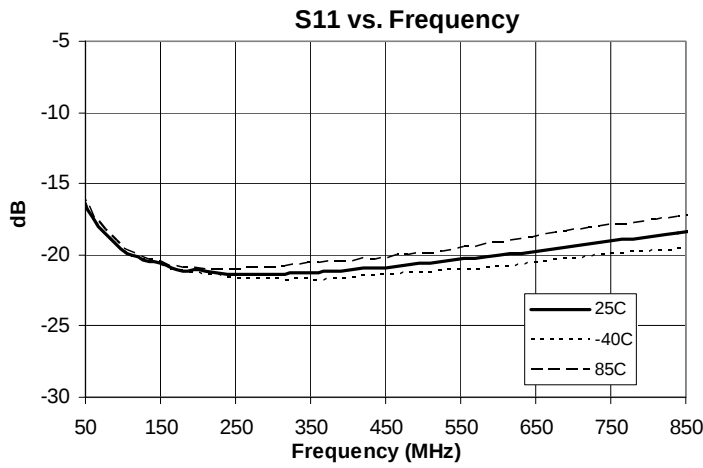
Test Conditions: $V_{CC} = 5V$ $I_D = 90mA$ Typ. OIP_3 Tone Spacing = 1MHz, P_{out} per tone = 0 dBm
 $T_L = 25^\circ C$ $Z_S = Z_L = 50$ Ohms



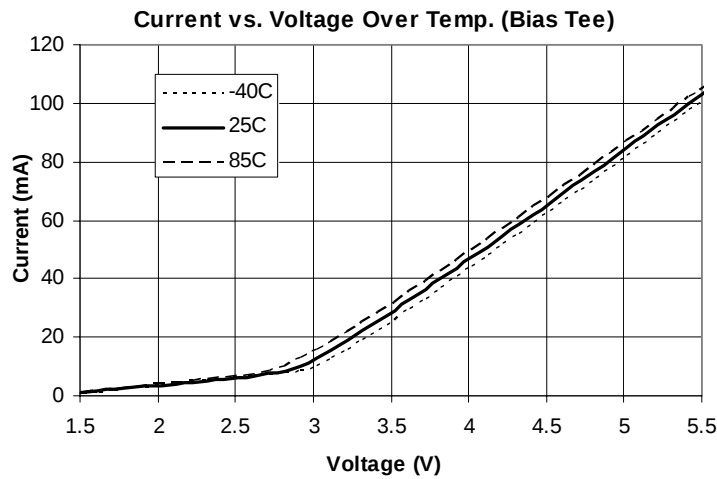
Data on Charts taken with 240 MHz App. Ckt.



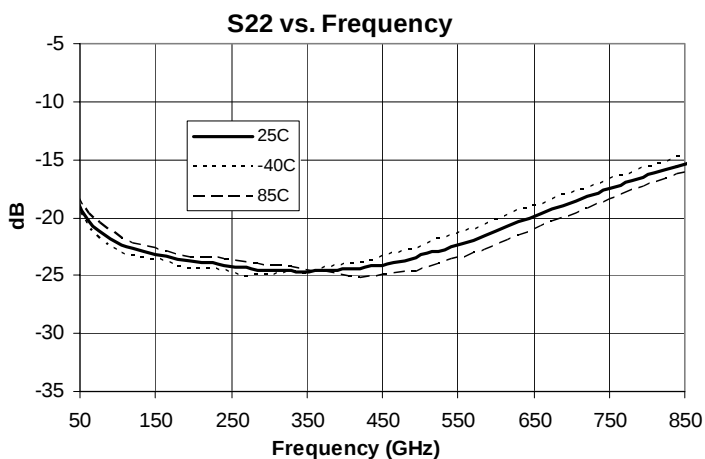
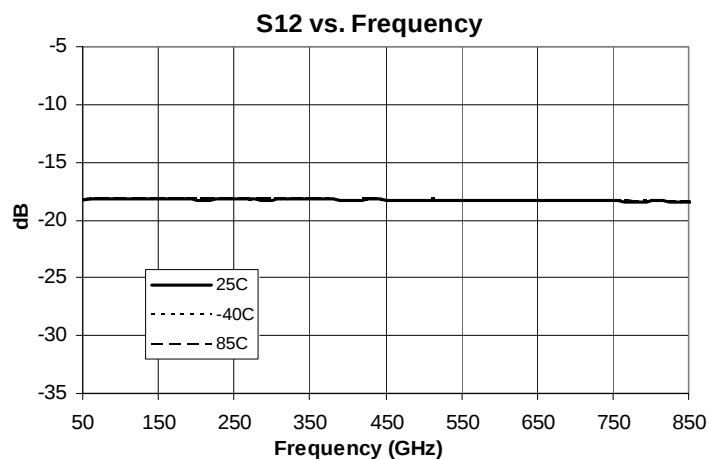
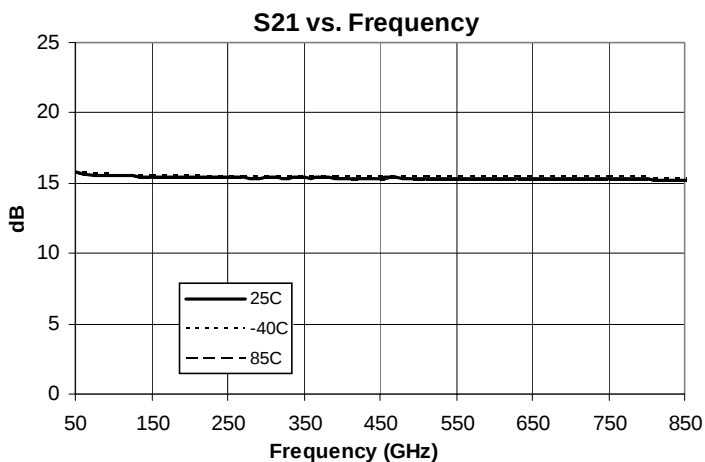
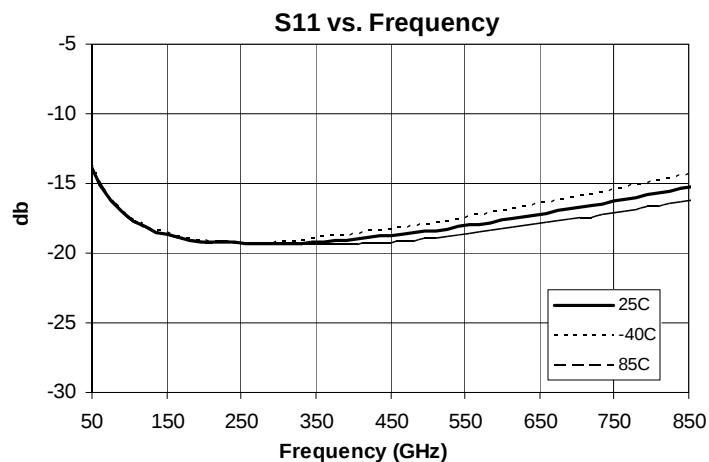
S-Parameters taken with Bias Tee over Temperature



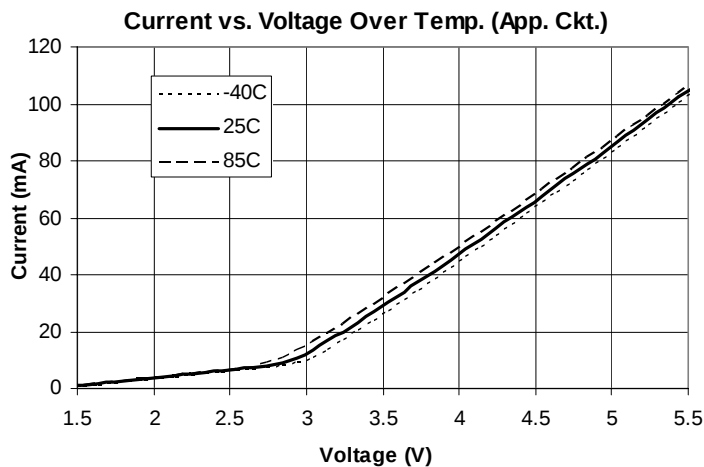
Device Current over Temperature (w/Bias Tee)



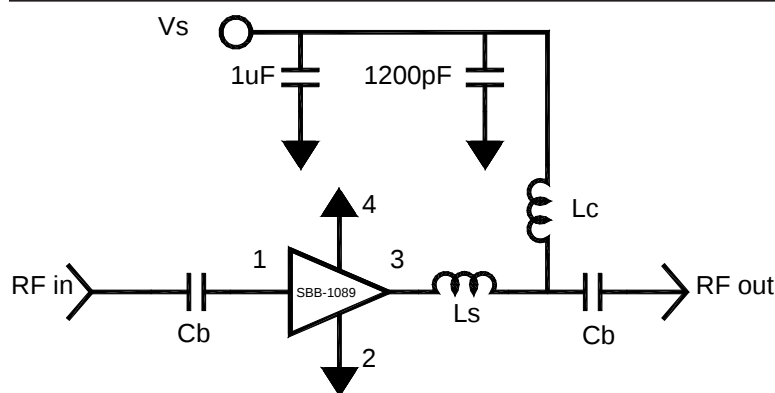
240 MHz Application Circuit S-Parameters over Temperature



Device Current over Temperature (w/App. Ckt.)



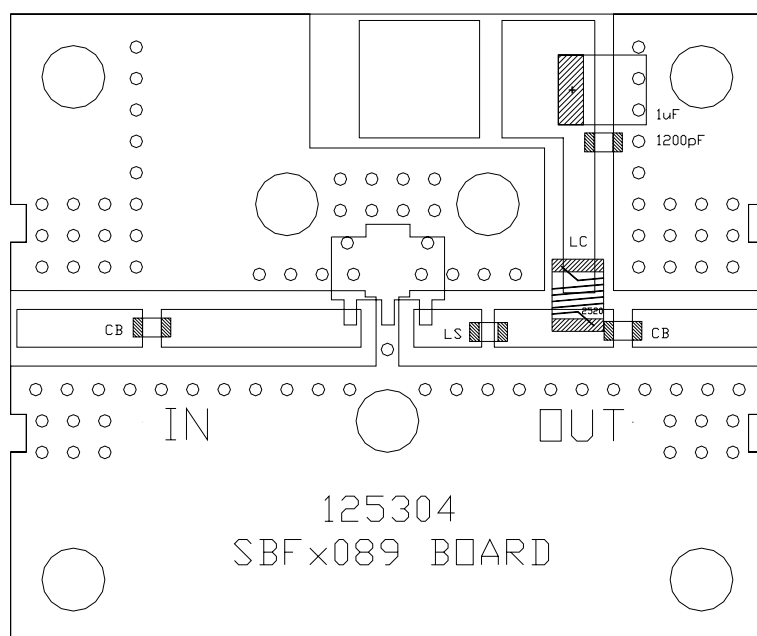
Application Schematic



Application Circuit Element Values

Reference Designator	Frequency (MHz) 50 to 850
C _B	8200pF
L _C	1200nH LS Coilcraft
L _S	2.7nH Toko

Evaluation Board Layout



Absolute Maximum Ratings

Parameter	Absolute Limit
Ma. Dvice Current (I _D)	110 mA
Max Device Voltage (V _D)	5.5 V
Max. RF Input Power	+12 dBm
Max. Operating Dissipated Power	0.61 W
Max. Junction Temp. (T _J)	+150°C
Operating Temp. Range (T _L)	-40°C to +85°C
Max. Storage Temp.	+150°C

Operation of this device beyond any one of these limits may cause permanent damage. For reliable continuous operation, the device voltage and current must not exceed the maximum operating values specified in the table on page one.
Bias Conditions should also satisfy the following expression:

$$I_D V_D < (T_J - T_L) / R_{TH}, j-l \quad T_L = T_{LEAD}$$



ESD Class 1C

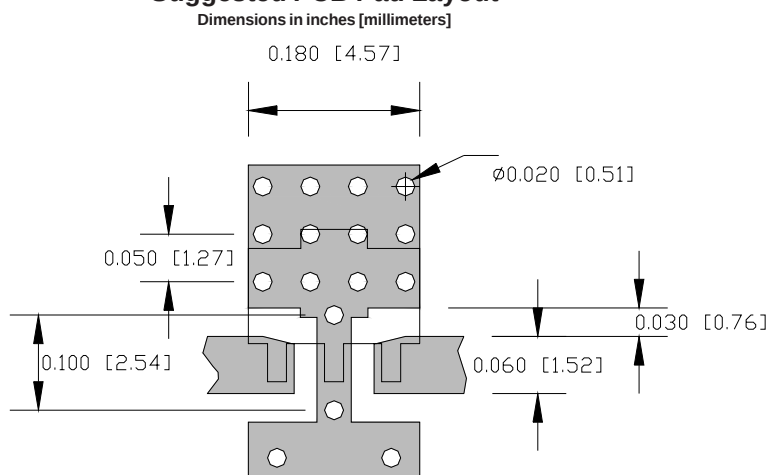
Appropriate precautions in handling, packaging and testing devices must be observed.

Mounting Instructions

1. Solder the copper pad on the backside of the device package to the ground plane.
2. Use a large ground pad area with many plated through-holes as shown.
3. We recommend 1 or 2 ounce copper. Measurement for this datasheet were made on a 31 mil thick FR-4 board with 1 ounce copper on both sides.

MSL (Moisture Sensitivity Level) Rating: Level 1

Suggested PCB Pad Layout

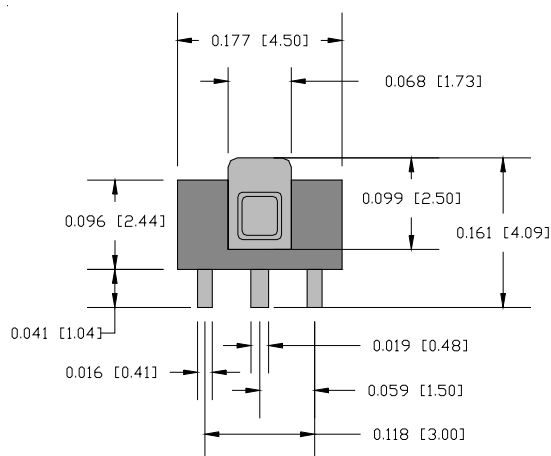


Nominal Package Dimensions

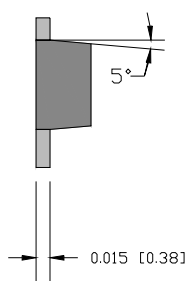
Dimensions in inches (millimeters)

Refer to package drawing posted at www.sirenza.com for tolerances

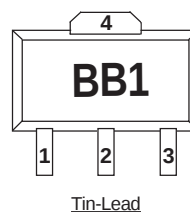
Bottom View



Side View



Package Marking



Part Number Ordering Information

Part Number	Reel Size	Devices / Reel
SBB-1089	7"	1000
SBB-1089Z	7"	1000

Pin #	Function	Description
1	RF IN	RF input pin. This pin requires the use of an external DC blocking capacitor chosen for the frequency of operation.
2, 4	GND	Connection to ground. Use via holes for best performance to reduce lead inductance as close to ground leads as possible.
3	RF OUT/ BIAS	RF output and bias pin. DC voltage is present on this pin, therefore a DC blocking capacitor is necessary for proper operation.